

PbS near-infrared detector

Single-Pixel thin-film encapsulated on PCB

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Features

- COB for direct PCB mounting
- Castellated holes for easy soldering
- High durability for rugged operation
- Very high sensitivity
- Room temperature operation

Applications

- Flame monitoring
- Flame and spark detection
- Gas detection and analysis
- Spectroscopy
- Temperature measurement
- Moisture measurement

Electrical and optical characteristics

Type No.	Active area [mm x mm]	Peak responsivity S [V/W]	
		Typ.	Min.
PbS005005 BC_PCB	0.5 x 0.5	$16 \cdot 10^5$	$10 \cdot 10^5$

- Measured with 1550 nm LED, incident power $16 \mu\text{W}/\text{cm}^2$
- Measured in a voltage divider circuit with 50 V/mm
- Photo responsivity and detectivity are measured with constant load resistance ($R_L = 1 \text{ M}\Omega$) and calculated for matched resistance

Element temperature [°C]	Peak wave-length λ_P [μm]	20% cut-off wavelength λ_C [μm]	Peak D^* (620 Hz, 1 Hz) [$\text{cm}\cdot\text{Hz}^{1/2}/\text{W}$]		Time constant [μs]	Dark resistance R_D [$\text{M}\Omega$]
	Typ.	Typ.	Typ.	Min.	Typ.	
22	2.7	2.9	$1 \cdot 10^{11}$	$0.8 \cdot 10^{11}$	200	0.3 - 3

COB on PCB attachment

- Use clean, soft rubber tip for pick and place handling
- UV-curing is not suitable due to permanent damage by UV light exposure
- Element temperature should never exceed $+70^\circ\text{C}$

Soldering

- Product is not compatible with reflow soldering
- Element temperature should never exceed $+70^\circ\text{C}$
- Detector should not be exposed to prolonged heat
- Exposing detector to flux damages thin-film encapsulation
- Recommendation: Careful hand soldering with low flux solder and short soldering time

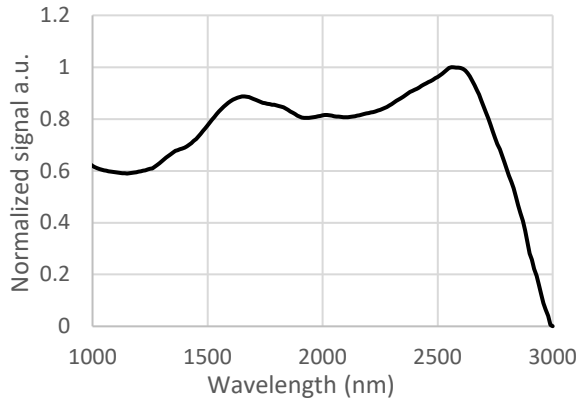
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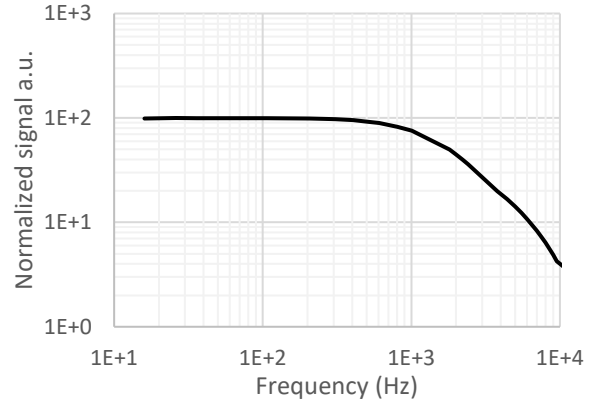
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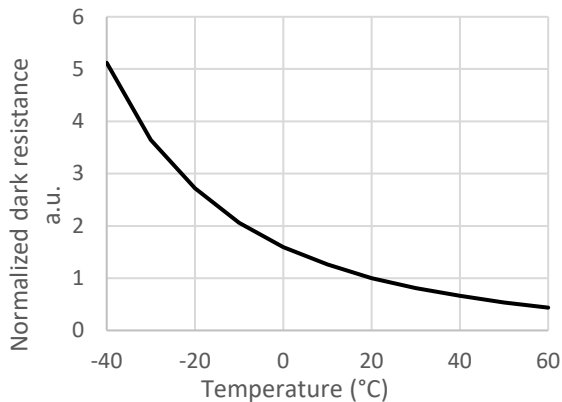
Typical spectral response



Typical frequency response



Typical resistance change over temperature



Storage

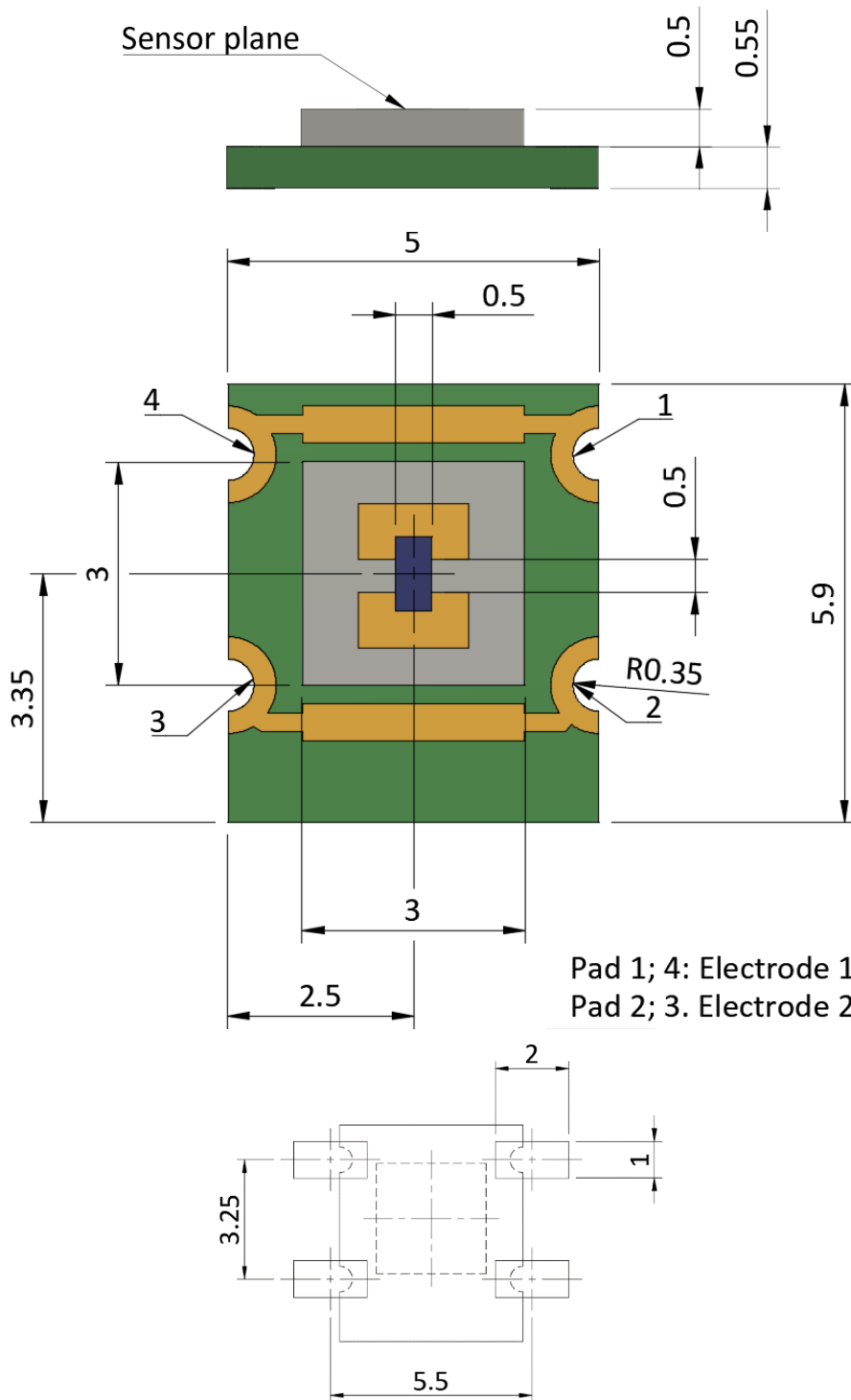
- Storage temperature: -55°C to +70°C
- Exposure to UV light results in permanent damage
- Prolonged exposure to visible light results in temporary low dark resistance

Handling

- Active area is scratch sensitive, protect top surface from any mechanical contact
- Ensure dust-free environment for device handling
- Operating temperature: -30°C to +70°C

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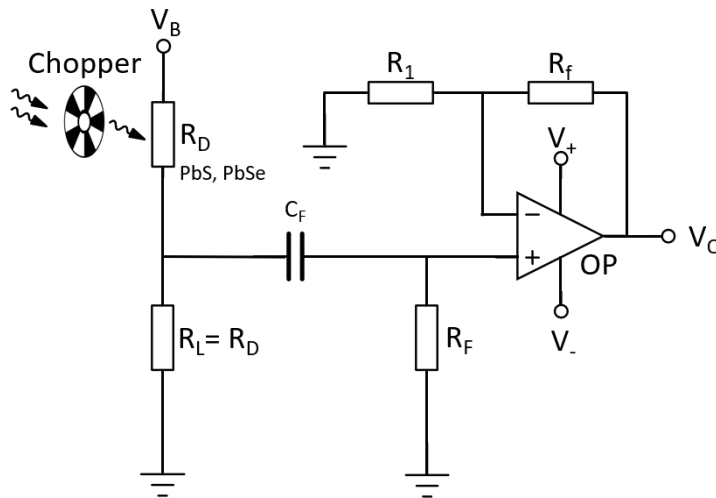
Mechanical outlines and land pattern (mm)



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Exemplary circuit



- V_B : Bias voltage
- V_O : Output voltage
- R_D : Dark resistance of the detector
- R_L : Load resistor
- C_F : Filter capacitor
- R_F : Filter resistor
- R_f : Feedback resistor
- R_1 : Gain resistor

Regulatory

For the use of Hertzstück™ PbS and PbSe infrared photodetectors in medical devices, monitoring and control instruments and consumer applications RoHS exemptions apply.

For automotive applications Hertzstück™ PbS and PbSe infrared photodetectors fall under ELV exemption.